# AN3810K

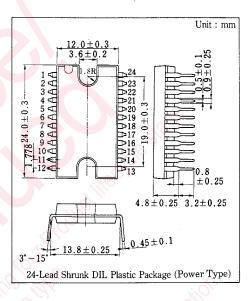
### VTR Cylinder Motor Drive Circuit

#### Outline

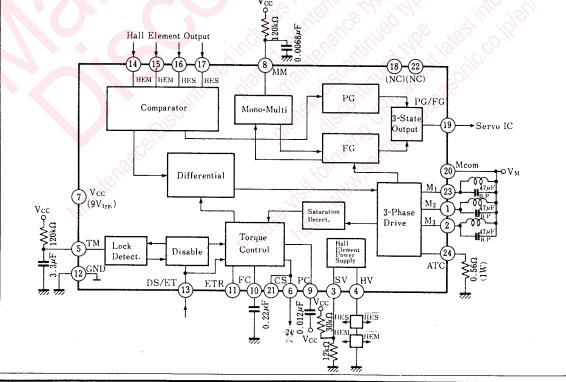
The AN3810K is an integrated circuit designed for a VCR cylinder direct-drive motor drive circuit.

#### Features

- Built-in 3-phase motor drive circuit
- Built-in PG and FG generator circuit
- Built-in motor lock detector circuit
- Built-in hall element circuit



#### Block Diagram



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#### Pin

Pin No.	Pin Name	Pin No.	Pin Name		
1	Drive Output 2	13	Torque. Control/Disable		
2	Drive Output 3	14	H. <mark>E.</mark> Input		
3	H.E. Power Supply Control	15	H.E. Input		
4	H.E. Power Supply	16	H.E. Input		
5	Mono-Multi Cap.	17	H.E. Input		
6	Current Detection	18	NC		
7	V <sub>cc</sub>	19	PG/FG Output		
8	Mono-Multi	20	Voltage Supply for Motor		
. 9	Phase Compensation	21	Current Detection		
10	Soft Shart	22	NC		
11	Reference Voltage Input	23	Drive Output		
12	GND	24	ATC		

#### ■ Absolute Maximum Ratings (Ta=25℃)

Item	Symbol	Rating		Unit	Note
Supply voltage	V <sub>cc</sub>		14.4	v	
	V <sub>n-12</sub>	0	40	v	n=1, 2, 23
Circuit Voltage	V <sub>20-12</sub>	0	24	V	
Circuit Current	ĺn	0	1500	mA	n=1, 2, 23
Power Dissipation	PD	2000		mW	
Operating Ambient Temperature	Topr	-20~+75		°C	
Storage Temperature	T <sub>stg</sub>	-55~+150		°C	

#### **Electrical Characteristics** $(V_{cc} = 9V, Ta = 25^{\circ}C)$

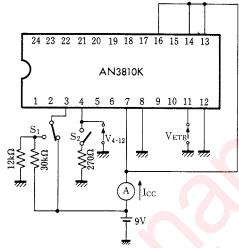
Item	Symbol	Test Circuit	Condition	min.	typ.	max.	Unit
Total Current	Icc*	1		6	XO	16	∑ mA
Output Saturation Temperature	V <sub>()(set)</sub>	2	lo=1A	$\mathcal{O}$	$\langle \mathcal{O}_{i} \rangle$	c	V
ATC Limit Voltage	V <sub>lim</sub>	2	V <sub>ET</sub> =0V (in Full Torque Command)	0.41	2	0.53	V
Input/Output Transfer Gain	Au	2	$R_a=0.47\Omega$	0.9	3	1.4	
Saturation Detection Gain	Ad	3		0.5	No.	1.5	
HV Output Voltage	VIIV	1	$V_{SV} = 2.6V, R_{HV} = 270\Omega$	2.2		2.6	v
HV Protection Voltage	Vprot	1	V <sub>Sv</sub> =V <sub>cc</sub>	3.3		4.3	v
DS Input Level Voltage	V <sub>DS</sub>	2		3.1		4.1	v
ETR Voltage	VETR	1		2.1		2.9	V
ET Offset Voltage	VotET	2	· // · · /	-30		30	тıV
HEM-HEM Comparator Offset Voltage	VoffM	4		-6		6	mV
HES-HEM Comparator Offset Voltage	VoffS	4		-6		6	mV
PG/FG 3-Value Output Voltage(1)	V <sub>он</sub>	4	$I_{19} = \pm 10 \mu A$	4.2			V
PG/FG 3-Value Output Voltage(2)	Vom	4	$\mathbf{J}_{19} = \pm 10 \mu \mathbf{A}$	2.1		2.9	v
PG/FG 3-Value Output Voltage(3)	Vol		$I_{19} = \pm 10 \mu A$			1	V
MM Threshold Voltage	V <sub>MM</sub>	5		3.8		4.6	<u>v</u>
BFG Fetch Voltage	V <sub>BFG</sub>	4	V <sub>M</sub> =9V	0.5		1.2	v
TM Threshold Voltage	V <sub>TM</sub>	5		4.1		4.9	V
ATC Residual Voltage	V <sub>idle</sub>	2		0		5	mV
ET Input Bias Current	I <sub>et</sub>			1		-10	μA
HEM. HEM. HES. and HES Input Bias Voltage	I <sub>B</sub>		· V 9 - 12W			-10	μA

Note) Range of the Operating Supply Voltage : V<sub>CC(opr)</sub> = 8 ~13V

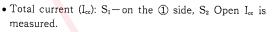
\*The Supply Current to the Hall element is not included.

## IC's FOR VTR

Test Circuit 1 (I<sub>CC</sub>)



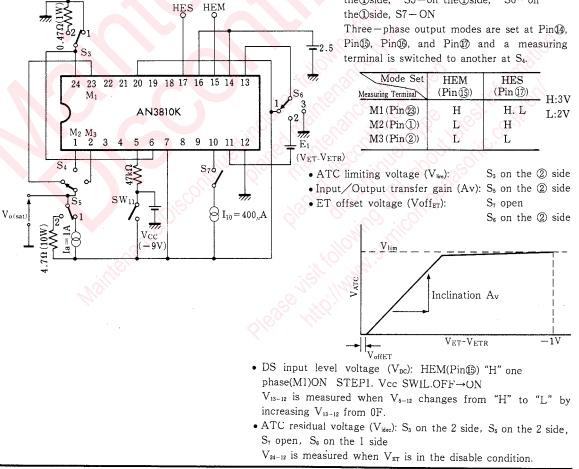
Test Circuit 2 (V<sub>O(set)</sub>, V<sub>lim</sub>, A<sub>1</sub>, V<sub>DS</sub>, V<sub>OFFET</sub>, V<sub>idle</sub>)



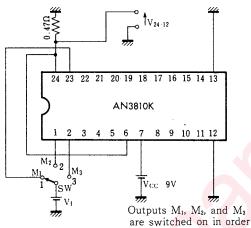
- HV output voltage (V<sub>HV</sub>):  $S_1$ -on the O side,  $S_2$ Short  $V_{4-12}$  is measured.
- HV protection voltage (Vprot): S<sub>1</sub>-on the (1) side, S<sub>2</sub> Open V<sub>4-12</sub> is measured.
- ETR voltage (V<sub>ETR</sub>): V<sub>ETR</sub> is measured.

the 1 side, S5-on the 1 side, S6-on the (1) side, S7-ON Three-phase output modes are set at Pin(4), Pin(5, Pin(6, and Pin(7) and a measuring terminal is switched to another at S<sub>4</sub>. Mode Set HEM HES

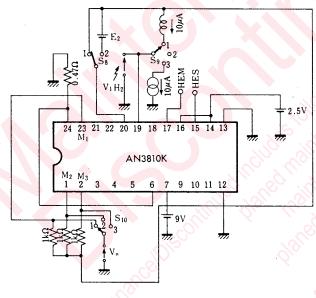
• Output saturation voltage (V<sub>o(sat)</sub>): S3-on



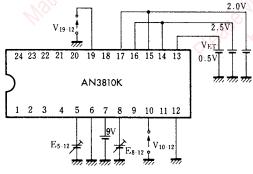
Test Circuit 3 (A<sub>d</sub>)



Test Circuit 4 (V<sub>offM</sub>, V<sub>offS</sub>, V<sub>OH</sub>, V<sub>OM</sub>, V<sub>OL</sub>, V<sub>BFG</sub>)



#### Test Circuit 5 (V<sub>MM</sub>, V<sub>TM</sub>)



- HEM-HEM Comparator offset voltage (Volf<sub>N</sub>):  $S_8$  on the (Dside
- HES-HES

Comparator offset voltage (Volfs): S8 on the (Dside HEM:L (2V)

Confirmed that Vo factuares as the HES and HEM terminal voltage vary by±5mV

Voff <sub>M</sub>	НЕМ	H(2.5V+5mV) - L(2.5V-5mV)
	S <sub>10</sub> -on the 1 side (M1)	L H
V-FC	HES	H(2.5V+5mV) - L(2.5V-5mV)
Voff <sub>S</sub>	S <sub>10</sub> -on the 2 side (M2)	L G- H

VOH, VOM, VOL

PG/FG 3 Value Outp VOH	(1)		HES H	HEM H	MM H
VOM	(2)	S₅-on the 1 side	L	L	H
VOL	(3)		L	L	L

 $V_{19-12}$  where  $S_9$  is on the 1, 2, or 3 side HES, HEM H:3V, L:2V H:5.2V L:3.2V

MM

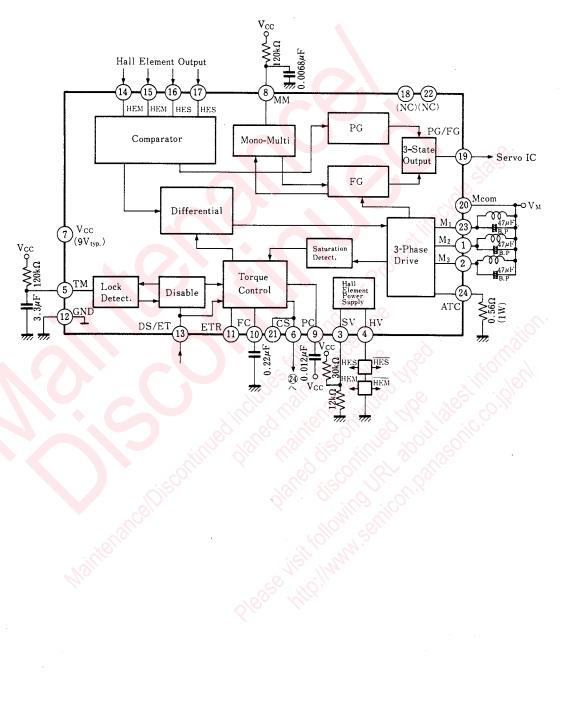
• V<sub>BFG</sub>

Measure E2 when it is increased from 0V and V19-12 is changed from L to M. Test Circuit 5.

- MM threshold voltage (V\_MM): Measure  $E_{8-12}$  when  $V_{18-12}$ changes from L to H by increasing Es-12 from 0V gradually.
- TM threshold voltage ( $V_{TM}$ ): Measure  $E_{8-12}$  when  $V_{10-12}$ changes from H to L by increasing Es-12 from 0V gradually.

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#### Application Circuit



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